TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC2644

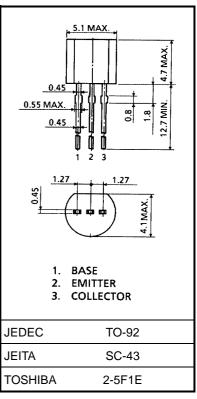
VHF~UHF Band Wideband Amplifier Applications

Unit: mm

- High gain
- Low IMD
- fT = 4 GHz (typ.)

Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|-----------------------------|------------------|---------|------|
| Collector-base voltage | V_{CBO} | 25 | V |
| Collector-emitter voltage | V_{CEO} | 12 | V |
| Emitter-base voltage | V _{EBO} | 3.0 | V |
| Collector current | IC | 120 | mA |
| Emitter current | ΙΒ | 40 | mA |
| Collector power dissipation | P _C | 0.5 | W |
| Junction temperature | Tj | 125 | °C |
| Storage temperature range | T _{stg} | -55~125 | °C |



Weight: 0.21 g (typ.)

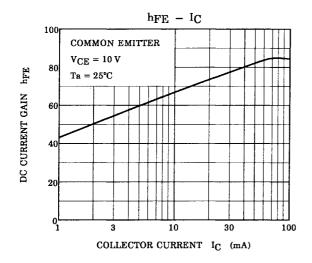
Microwave Characteristics (Ta = 25°C)

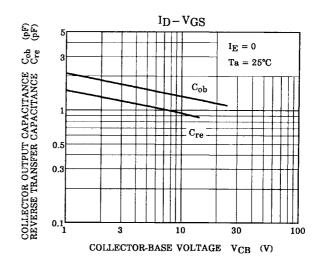
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------------------|-------------------------------------|---|-----|------|-----|------|
| Transition frequency | f _T | V _{CE} = 10 V, I _C = 30 mA | _ | 4.0 | _ | GHz |
| Insertion gain | S _{21e} ² (1) | $V_{CE} = 10 \text{ V}, I_{C} = 30 \text{ mA}, f = 0.5 \text{ GHz}$ | _ | 14.0 | _ | dB |
| | S _{21e} ² (2) | $V_{CE} = 10 \text{ V}, I_{C} = 30 \text{ mA}, f = 1 \text{ GHz}$ | _ | 8.5 | _ | |
| Noise figure | NF (1) | $V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}, f = 0.5 \text{ GHz}$ | _ | 2.3 | _ | - dB |
| | NF (2) | V _{CE} = 10 V, I _C = 10 mA, f = 1 GHz | _ | 3.0 | _ | |

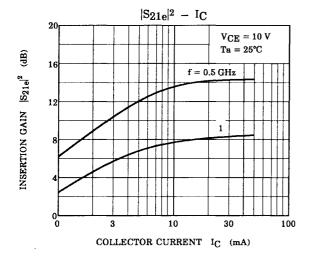
Electrical Characteristics (Ta = 25°C)

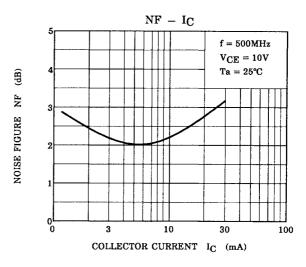
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------------|------------------|--|-----|------|-----|------|
| Collector cut-off current | I _{CBO} | $V_{CB} = 10 \text{ V}, I_{E} = 0$ | _ | _ | 1 | μА |
| Emitter cut-off current | I _{EBO} | $V_{EB} = 1.0 \text{ V}, I_{C} = 0$ | _ | _ | 10 | μА |
| DC current gain | h _{FE} | $V_{CE} = 5 \text{ V}, I_{C} = 50 \text{ mA}$ | 20 | 50 | _ | |
| Collector output capacitance | C _{ob} | V _{CB} = 10 V, I _E = 0, f = 1 MHz (Note) | _ | 1.6 | _ | pF |
| Reverse transfer capacitance | C _{re} | | _ | 1.1 | _ | pF |

Note: C_{re} is measured by 3 terminal method with capacitance bridge.



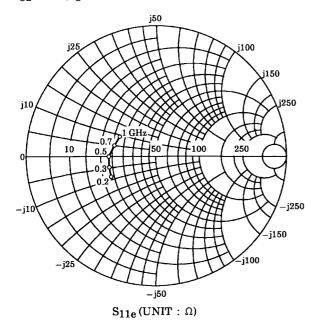


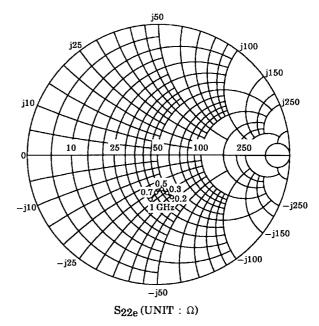


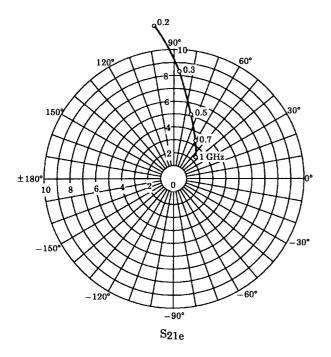


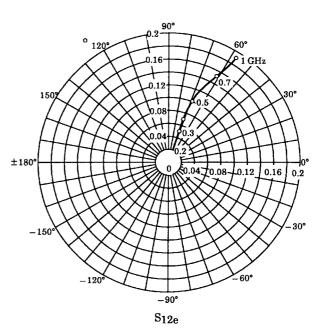
Common Emitter Small S-Parameters of 2SC2644

 $V_{CE}=10\ V,\ I_{C}=30\ mA$









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